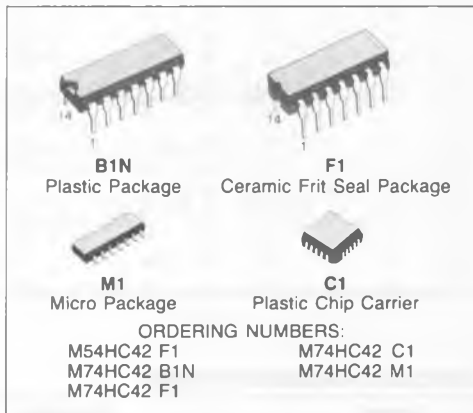
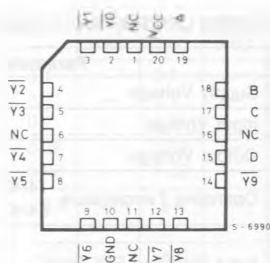
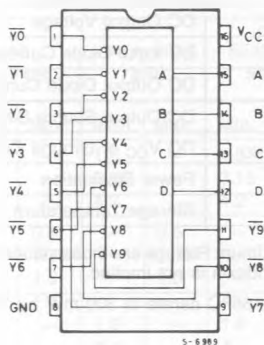


BCD-TO-DECIMAL DECODER

- **HIGH SPEED**
 $t_{PD} = 17 \text{ ns (TYP.) at } V_{CC} = 5V$
- **LOW POWER DISSIPATION**
 $I_{CC} = 4 \mu\text{A (MAX.) at } T_A = 25^\circ\text{C}$
- **HIGH NOISE IMMUNITY**
 $V_{NIH} = V_{NIL} = 28\% V_{CC} \text{ (MIN.)}$
- **OUTPUT DRIVE CAPABILITY**
 10 LSTTL LOADS
- **SYMMETRICAL OUTPUT IMPEDANCE**
 $|I_{OH}| = I_{OL} = 4 \text{ mA (MIN.)}$
- **BALANCED PROPAGATION DELAYS**
 $t_{PLH} = t_{PHL}$
- **WIDE OPERATING VOLTAGE RANGE**
 $V_{CC} \text{ (OPR)} = 2V \text{ to } 6V$
- **PIN AND FUNCTION COMPATIBLE**
 WITH 54/74LS42



PIN CONNECTIONS (top view)



NC =
 No Internal
 Connection

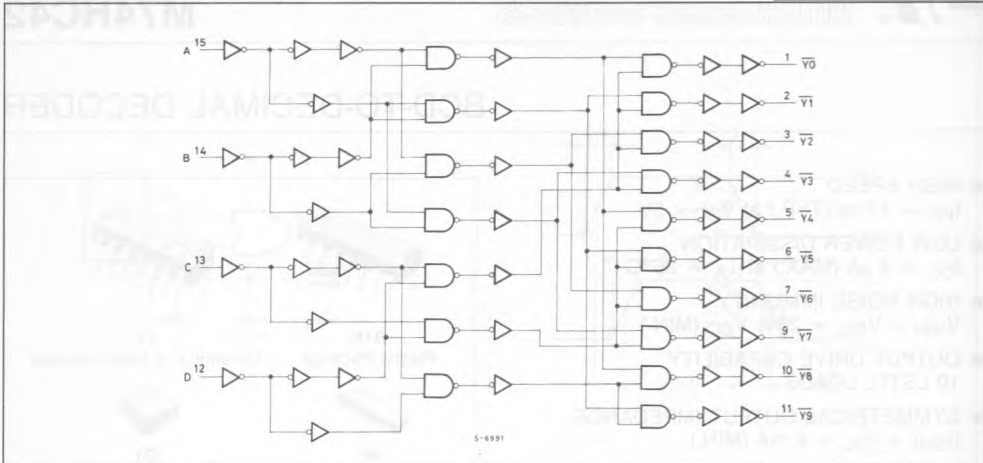
DESCRIPTION

The M54/74HC42 is a high speed CMOS BCD-TO-DECIMAL DECODER fabricated in silicon gate CMOS technology.

It has the same high speed performance of LSTTL combined with true CMOS low power consumption. BCD code applied to the four inputs A-D selects one of ten decimal outputs Y0-Y9, which goes low or fifteen gives a high level at all outputs. This device also can be used as a 3-to-8 LINE DECODER, when the D input is assigned as a disable input. This device is useful for code conversion, address decoding, memory selection, demultiplexing, or readout decoding.

All inputs are equipped with protection circuits against static discharge and transient excess voltage.

LOGIC DIAGRAM



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage	-0.5 to 7	V
V_I	DC Input Voltage	-0.5 to $V_{CC} + 0.5$	V
V_O	DC Output Voltage	-0.5 to $V_{CC} + 0.5$	V
I_{IK}	DC Input Diode Current	± 20	mA
I_{OK}	DC Output Diode Current	± 20	mA
I_O	DC Output Source Sink Current Per Output Pin	± 25	mA
I_{CC} or I_{GND}	DC V_{CC} or Ground Current	± 50	mA
P_D	Power Dissipation	500 (*)	mW
T_{stg}	Storage Temperature	-65 to 150	$^{\circ}C$

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.

(*) 500 mW: $\equiv 65^{\circ}C$ derate to 300 mW by 10 mW/ $^{\circ}C$: $65^{\circ}C$ to $85^{\circ}C$

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Value	Unit	
V_{CC}	Supply Voltage	2 to 6	V	
V_I	Input Voltage	0 to V_{CC}	V	
V_O	Output Voltage	0 to V_{CC}	V	
T_A	Operating Temperature	74HC Series 54HC Series	-40 to 85 -55 to 125	$^{\circ}C$
t_r, t_f	Input Rise and Fall Time	V_{CC} { 2 V 4.5V 6 V	0 to 1000 0 to 500 0 to 400	ns

TRUTH TABLE

CODE No.	BCD INPUTS				DECIMAL OUTPUTS									
	D	C	B	A	\bar{Y}	$\bar{Y}1$	$\bar{Y}2$	$\bar{Y}3$	$\bar{Y}4$	$\bar{Y}5$	$\bar{Y}6$	$\bar{Y}7$	$\bar{Y}8$	$\bar{Y}9$
0	L	L	L	L	L	H	H	H	H	H	H	H	H	H
1	L	L	L	H	H	L	H	H	H	H	H	H	H	H
2	L	L	H	L	H	H	H	L	H	H	H	H	H	H
3	L	L	H	H	H	H	H	L	H	H	H	H	H	H
4	L	H	L	L	H	H	H	H	L	H	H	H	H	H
5	L	H	L	H	H	H	H	H	H	L	H	H	H	H
6	L	H	H	L	H	H	H	H	H	H	L	H	H	H
7	L	H	H	H	H	H	H	H	H	H	H	L	H	H
8	H	L	L	L	L	H	H	H	H	H	H	H	L	H
9	H	L	L	H	H	H	H	H	H	H	H	H	H	L
10	H	L	H	L	H	H	H	H	H	H	H	H	H	H
11	H	L	H	H	H	H	H	H	H	H	H	H	H	H
12	H	H	L	L	H	H	H	H	H	H	H	H	H	H
13	H	H	L	H	H	H	H	H	H	H	H	H	H	H
14	H	H	H	L	H	H	H	H	H	H	H	H	H	H
15	H	H	H	H	H	H	H	H	H	H	H	H	H	H

DC SPECIFICATIONS

Symbol	Parameter	V_{CC}	Test Condition	$T_A = 25^\circ\text{C}$ 54HC and 74HC			- 40 to 85°C 74HC		- 55 to 125°C 54HC		Unit	
				Min.	Typ.	Max.	Min.	Max.	Min.	Max.		
V_{IH}	High Level Input Voltage	2.0 4.5 6.0		1.5 3.15 4.2	— — —	— — —	1.5 3.15 4.2	— — —	1.5 3.15 4.2	— — —	V	
V_{IL}	Low Level Input Voltage	2.0 4.5 6.0		— — —	— — —	0.5 1.35 1.8	— — —	0.5 1.35 1.8	— — —	0.5 1.35 1.8	V	
V_{OH}	High Level Output Voltage	2.0 4.5 6.0 4.5 6.0	V_I	I_O - 20 μA	1.9	2.0	—	1.9	—	1.9	—	V
			V_{IH} or V_{IL}		4.4 5.9	4.5 6.0	— —	4.4 5.9	— —	4.4 5.9	— —	
			V_{IL}	- 4.0 mA	4.18	4.31	—	4.13	—	4.10	—	
				- 5.2 mA	5.68	5.8	—	5.63	—	5.60	—	
V_{OL}	Low Level Output Voltage	2.0 4.5 6.0 4.5 6.0	V_{IH} or V_{IL}	20 μA	— — —	0 0 0	0.1 0.1 0.1	— — —	0.1 0.1 0.1	— — —	0.1 0.1 0.1	V
			V_{IL}	4.0 mA	—	0.17	0.26	—	0.33	—	0.40	
				5.2 mA	—	0.18	0.26	—	0.33	—	0.40	
			I_I	Input Leakage Current	6.0	$V_I = V_{CC}$ or GND	—	—	± 0.1	—	± 1	
I_{CC}	Quiescent Supply Current	6.0	$V_I = V_{CC}$ or GND	—	—	4	—	40	—	80	μA	

AC ELECTRICAL CHARACTERISTICS ($V_{CC} = 5V$, $T_A = 25^\circ C$, $C_L = 15pF$, Input $t_r = t_f = 6ns$)

Symbol	Parameter	54HC and 74HC			Unit
		Min.	Typ.	Max.	
t_{TLH} t_{THL}	Output Transition Time		4	8	ns
t_{PLH} t_{PHL}	Propagation Delay Time		15	24	ns

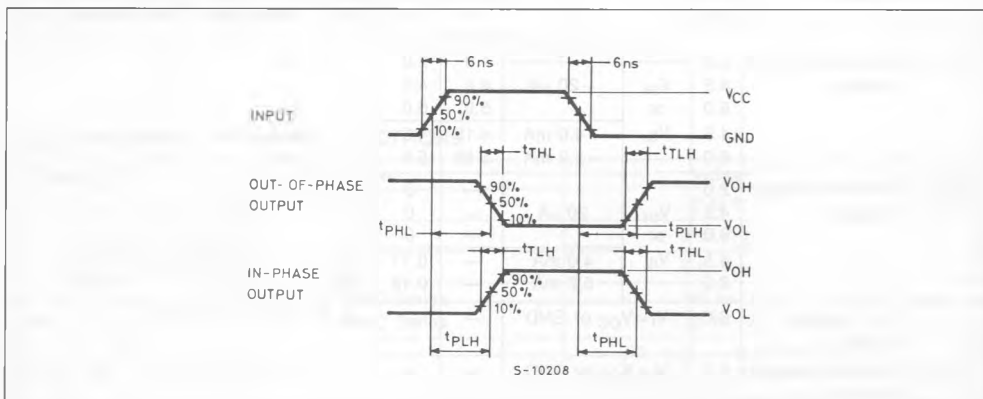
AC ELECTRICAL CHARACTERISTICS ($C_L = 50pF$, Input $t_r = t_f = 6ns$)

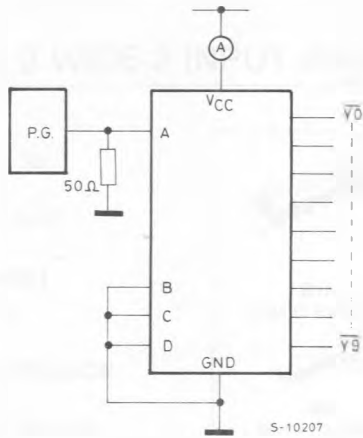
Symbol	Parameter	V_{CC}	Test Condition	$T_A = 25^\circ C$ 54HC and 74HC			- 40 to 85°C 74HC		- 55 to 125°C 54HC		Unit
				Min.	Typ.	Max.	Min.	Max.	Min.	Max.	
t_{TLH} t_{THL}	Output Transition Time	2.0 4.5 6.0		— — —	30 8 7	75 15 13	— — —	95 19 16	— — —	110 22 19	ns
t_{PLH} t_{PHL}	Propagation Delay Time	2.0 4.5 6.0		— — —	76 19 16	145 29 25	— — —	180 36 31	— — —	220 44 38	ns
C_{IN}	Input Capacitance			—	5	10	—	10	—	10	pF
$C_{PD} (*)$	Power Dissipation Capacitance			—	67	—	—	—	—	—	pF

Note (*) C_{PD} is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to Test Circuit)

Average operating current can be obtained by the following equation $I_{CC} (Opr.) = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

SWITCHING CHARACTERISTICS TEST CIRCUIT



TEST CIRCUIT I_{CC} (Opr.)

INPUT WAVEFORM IS THE SAME AS THAT IN CASE OF SWITCHING CHARACTERISTICS TEST.